Sulfur and sulfur-oxide compounds as potential optically active defects on **SWCNTs**

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Semiconducting single-walled carbon nanotubes (SWCNT) containing sp³-type defects are a promising class of optoelectronic materials, demonstrating single photon emission and long-lived spins. The defect introduces new optical transitions due to both symmetry breaking induced band splitting and introduction of in-gap electronic states. We investigate sulfur-oxide containing compounds as a new class of optically active dopants on (6,5) SWCNT. The SWCNT is exposed to sodium dodecyl sulfate with the resulting compound displaying a red-shifted and bright photoluminescence peak that is characteristic of $sp³$ doping. Density functional theory calculations are then performed on the adsorbed compounds that may arise $(S, SO, SO₂ and SO₃)$). These calculations indicate that the two smallest molecules strongly bind to the SWCNT with binding energies of ∼ 1.5−1.7 eV and 0.56 eV for S and SO, respectively. Moreover, these adsorbates introduce in-gap electronic states into the bandstructure of the tube consistent with the measured red-shift of $(0.1 - 0.3)$ eV. Our study suggests that sulfur-based compounds are promising new dopants for (6,5) SWCNT with tunable electronic properties.

Doped semiconducting single walled carbon nanotubes $(SWCNT)$ show promise as optical sensors^{[1](#page-4-0)} and quantum light emitters^{[2](#page-4-1)} due to their controlled sensitivity to adsor-bates and tunable electron fluorescence.^{[1](#page-4-0)[,3](#page-4-2)[–5](#page-4-3)} For this class of materials, covalent defects introduce new optical transitions that modify the optical absorption spectrum and increase the photoluminescence (PL) efficiency.^{[4](#page-4-4)[–11](#page-4-5)} As such, defective SWCNT display high purity single photon emission (SPE) with improved quantum yields 3,4,8,9,11 3,4,8,9,11 3,4,8,9,11 3,4,8,9,11 3,4,8,9,11 3,4,8,9,11 3,4,8,9,11 for incorporation into bioelectronic devices, 12,13 12,13 12,13 12,13 sensors^{[1](#page-4-0)} and quantum devices. $2,14$ $2,14$

Dopants are typically introduced to the SWCNT through breaking of one carbon $sp²$ bond and attaching a ligand that creates an $sp³$ defect site. This defect can create a deep trap state (∼ 100 meV) that localizes the exciton and significantly improves $SPE^{2,3,7,10,15-17}$ $SPE^{2,3,7,10,15-17}$ $SPE^{2,3,7,10,15-17}$ $SPE^{2,3,7,10,15-17}$ $SPE^{2,3,7,10,15-17}$ $SPE^{2,3,7,10,15-17}$ $SPE^{2,3,7,10,15-17}$ $SPE^{2,3,7,10,15-17}$ The most common $sp³$ defects are atomic defects, such as hydrogen^{[18](#page-4-15)} and oxygen,^{[4,](#page-4-4)[7](#page-4-11)[,9,](#page-4-7)[16](#page-4-16)} and functionalized aryl groups.[8,](#page-4-6)[10,](#page-4-12)[17](#page-4-14)[,19](#page-4-17)[,20](#page-4-18) The atomic defects, particularly oxygen, form at stable locations on the tube, with a red-shift of the photoluminescence (PL) peak and enhanced photon emissions. $4,7,9$ $4,7,9$ $4,7,9$ However, the resulting electronic properties of atomic defects synthesized thus far are determined only by the defect binding configuration, limiting

the ability to modify their electronic properties.^{[16](#page-4-16)} On the other hand, aryl groups and carbon chain dopants offer stable defect sites with slightly more tunability through their functional groups.^{[2,](#page-4-1)[8](#page-4-6)[,10](#page-4-12)[,17](#page-4-14)[,19](#page-4-17)} However, the electronic structure of these molecular-based dopants is hard to control when passivated, $5,21-23$ $5,21-23$ $5,21-23$ and has been shown to be defect-independent in certain unpassivated aryl groups.^{[24](#page-4-21)} Given the close similarities between the limitations of atomic and aryl sp³ -defects, we explore atomic-like defects, which may provide a practical path for creating doped SWCNT for lower cost of materials that can be produced on an industrial scale.

In this Letter, we present an investigation of new sulfur-oxide-based dopants for (6,5) SWCNT. Similar to oxygen, sulfur oxides are easy to obtain as reactants and so we investigate whether these defects can produce optically active states similar to prior $sp³$ defects. By introduction of sodium dodecyl sulfate to solution-phase (6,5) SWCNT, which we expect results in $SO₂$ adsorption on the surface, we show that a new doped species is created with the desired red-shifted emissions spectrum as shown in Figure [1.](#page-1-0) Within density functional theory (DFT), we study the adsorption of sulfur-oxide derivatives that may arise $(S, SO, SO₂, SO₃)$ in order to determine the most likely species that has been synthesized. We predict that the larger two molecules studied, SO_2 and SO_3 , are weakly physisorbed to the SWCNT, with little to

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Figure 1. Photoluminescence spectrum of pristine (6,5) SWCNT and (6,5) SWCNT after exposure to sodium dodecyl sulfate. The data for each plot was normalized such that the maximum intensity is 1 (see SI Fig S.1 for measured spectrum of the doped SWCNT). The pristine spectrum was extracted from Ref [7.](#page-4-11)

no electronic interaction to the tube. In contrast, S and SO favorably bind to the tube with a red-shifted gap due to either defect-induced band splitting or introduction of an in-gap defect state. Thus, our study indicates that S and SO defects can be incorporated into and tune the optical properties of (6,5) SWCNT.

Figure [1](#page-1-0) presents the photoluminescence (PL) spectrum for the SO_x -doped (6,5) SWCNT compared with the pristine tube. The peak maximum is at 1105 nm (1.12 eV) with a low-energy shoulder at 1228 nm (1.0 eV) and another peak at 984 nm (1.26 eV) that is consistent with the pristine tube E_{11} peak^{[7](#page-4-11)}. The fact that new transitions are introduced at $0.1 - 0.3$ eV below the pristine gap is consistent with sp3 doping of the (6,5) SWCNT.[7](#page-4-11)[,16,](#page-4-16)[19](#page-4-17)[,25](#page-5-0) The details of synthesis and characterization of this system will be published elsewhere. Here, we focus on better understanding the chemical nature and electronic structure of this new species from firstprinciples DFT simulations.

Figure $2(a)$ shows the different sulfur compounds considered along with their corresponding binding configuration relative to the SWCNT. We chose S , SO , $SO₂$, and SO³ because of prior spectroscopic studies combined with electron microscopy that determined SO_2 may decompose into these compounds on SWCNT. 26 26 26 We considered different possible configurations of the adsorbate and only show configurations with favorable binding here (see supporting information Section 2.1 for details on unbound structures). For the single sulfur atom, we considered epoxide-type and ether-type binding (structures 1 and 2), both of which have been shown to be energetically favorable locations for oxygen binding on (6,5) $SWCNT.¹⁶$ $SWCNT.¹⁶$ $SWCNT.¹⁶$ For the SO molecule, a four-member ringtype binding (structure 3) with the S and O each bound to one carbon atom was found to be favorable. For each S and SO configuration, we consider two different orien-

Table I. Adsorption energy (E_b) , band gap (E_{gap}) , and the energies of the highest valance band (E_{VBM}) and lowest unoccupied state (ELUS) for the defects considered in this work. The adsorption energies are defined such that a negative energy is bound (see Eq. (1)). All energies are in eV.

[a](#page-1-2)

^a The binding energy for $SO₂$ was calculated by subtracting off the hydrogen binding energy from the total binding energy. See computational details.

tations of the C-S-C bonds, along the long ('l') and short ('d') axes of the tube (see Fig. $2(b)$). For $SO₂$, three different binding configurations were found to be favorable: 1) the SO_2 attached to two carbons across a broken carbon bond via the two oxygen on the $SO₂$ labeled "OO-loop" (structure 4), inspired by the orientation of SO_2 bound to graphene sheets;^{[27,](#page-5-2)[28](#page-5-3)} 2) the episulfide-type binding, a modification of the epoxide-type binding of S (structure 5); and 3) with a hydrogen atom attached to a carbon atom neighboring the adsorption site, with the O 's on the $SO₂$ oriented to be in line with the hydrogen, labeled "Line-H" (structure 6), introduced to test whether H can increase the affinity of the adsorbate to the tube. Lastly, for SO_3 , a flat-type binding motivated by binding of $SO₃$ on graphene is found to be favorable $(\text{structure } 7).^{29}$ $(\text{structure } 7).^{29}$ $(\text{structure } 7).^{29}$

We present the binding energies of the sulfur compounds to (6,5) SWCNT in Table [I,](#page-1-3) calculated as,

$$
E_{\rm b} = E_{\rm CNT + SOx} - (E_{\rm CNT} + E_{\rm SOx}).\tag{1}
$$

Here, the $E_{\text{CNT+SOx}}$ is the total energy of the adsorbate on SWCNT, E_{CNT} is the total energy of the pristine tube, and E_{SO_X} is the total energy of the sulfur compound in vacuum.

The S atom is the most strongly bound to the tube, with binding energy ranging from -1.53 eV to -1.69 eV depending on the bonding arrangement (episulfide or thioether; 'l' or 'd' orientation). This value is greater than half of a C-S covalent bond energy of $\sim 2.7 \text{ eV},^{30,31}$ $\sim 2.7 \text{ eV},^{30,31}$ $\sim 2.7 \text{ eV},^{30,31}$ $\sim 2.7 \text{ eV},^{30,31}$ suggesting strong chemical bonding between the tube and S. For thioether-type adsorption, with the S arranged between a broken carbon-carbon bond, the binding is stronger along the short axis ('d') than along the long axis ('l') by 0.16 eV. This finding is consistent with previous studies of oxygen dopants on $(6,5)$ SWCNT, 16 16 16 and suggests that the binding of the sulfur on the CNT is in-

(b)

Figure 2. a) The orientation of the different sulfur compounds studied relative to the carbon atoms (R_x) of the SWCNT. b) Illustration of the two different orientations of the sulfur compounds relative to the SWCNT tube axis with a single sulfur atom shown as an example. The cylinder represents the (6,5) SWCNT.

fluenced by its orientation. This anisotropy is not present for the SO molecule, with both the 'l' and 'd' directions predicted to have a biding energy of -0.56 eV. SO₂ and SO³ display much weaker binding to the surface, more consistent with physisorption. For $SO₂$, all configurations studied were predicted to bind with energies ranging from -0.20 eV (no hydrogen) to -0.33 eV (with hydrogen), indicating that hydrogen only slightly enhances the bond strength. For SO_3 , the binding energy is similarly weak at -0.27 eV. That the larger two defects, SO_2 and $SO₃$, are physisorbed on the surface is consistent with previous studies on carbon nanotubes $32-36$ $32-36$

To better understand the binding of SO_x to $(6,5)$ SWCNT, Figure [3](#page-2-2) shows the bonding arrangements of select compounds including bond lengths (for all compounds see SI Table S.1). For the sake of comparison, we note that the S-C covalent bond length is $\sim 1.8 \text{ Å}.^{37}$ $\sim 1.8 \text{ Å}.^{37}$ $\sim 1.8 \text{ Å}.^{37}$ For the atomic S adsorbate, the bond length is $1.83 - 1.88$ A, close to the covalent bond length, with bond angle between the S and tube of $63.6^{\circ} - 66.4^{\circ}$ (depending on orientation). The S-C bond is slightly stretched for SO adsorption (\sim 2.05 Å) with the bond angles indicating a tilt towards one of the two carbons on the tube (S-R-R angle: $\sim 66^{\circ}$ and $\sim 71^{\circ}$), which we attribute to steric effects due to the presence of the oxygen atom. All the SO_2 and the $SO₃$ structures show an adsorption distance of \sim 3.0 Å away from the SWCNT surface, consistent with the weak binding. For SO_2 , the bond angles for the OOloop-d (S-R-R angle: 82.4° and 72.3°) and Episulfide-d $(S-R-R$ angle: 78.3 $^{\circ}$ and 75.9 $^{\circ}$) structures indicate the molecule adsorbs slightly off of the C-C bond with S in the hollow site, while the hydrogen passivated structure

Figure 3. The PBE-D3-predicted adsorption sites of the SO_x structures on (6,5) SWCNT. Relevant bond lengths are labeled.

shows the S in the $SO₂$ adsorbs on top of a carbon atom (S-R-R angle: 61.2° and 93.8°). SO₃ bond angles (S-R-R angle: 57.5° and 94.0°) also show adsorption of S on top of one of the carbons.

Next, we consider the impact of S, SO , SO_2 , and SO_3 on the electronic structure of (6,5) SWCNT. Based on the predicted bonding for the four sulfur compounds to the tube, we may expect that the S and SO compounds are most likely to occur due to their favorable binding energy and will impact the bandstructure most significantly due to their strong bond with the tube. The band structures of select low-energy configurations for the four compounds are shown in Fig. [4](#page-3-0) (see SI Figure S.5 for all band structures).

The near-gap states of the (6.5) SWCNT are of π type character with a two-fold degeneracy at $\mathbf{k} = 0$ due to the underlying graphitic structure. All the defects presented break the symmetry of the tube, leading to splitting of the nearly-degenerate valence and conduction bands, as has been reported previously for doped (6,5) SWCNT[5,](#page-4-3)[7–](#page-4-11)[9,](#page-4-7)[16,](#page-4-16)[18](#page-4-15)[,19](#page-4-17)[,25](#page-5-0) This splitting is largest for S and SO (see SI Figure S.4 for more details) as expected from the stronger binding and therefore stronger perturbation to the system. The maximum splitting of the conduction (valence) bands for S, ether-d, S, ether-l, and SO are 0.063 (0.051), 0.20 (0.11) and 0.038 (0.067) eV, respectively. The splitting of the bands for $SO₂$ is less than 4 meV for both valence and conduction bands, while for $SO₃$ it is 4 meV for the valence and 0.13 eV for the conduction band.

In addition to symmetry breaking-induced band splitting, both S and SO oriented with the 'l' orientation introduce a new unoccupied in-gap state associated with the defect into bandstructure, reducing the gap by up to 0.28 eV for S and 0.08 eV for SO. This in-gap state is associated with a localized defect-centered orbital hybridized with the SWCNT bands as shown in the orbital density plots below the bandstructure. This state is not present for S in the thioether-d configuration for which no defect-centered orbital is present near the gap. $SO₂$ also introduces an in-gap state; however, this is a flat band with an associated orbital density that is localized on the defect, indicating no interaction with the tube. For

Figure 4. PBE-predicted bandstructure for pristine (6,5) SWCNT and (6,5) SWCNT with the mostly likely adsorbate structures for S, SO, SO₂, and SO₃. Occupied pristine-like valence bands and unoccupied conduction bands are shown in red and blue, respectively, while unoccupied states localized on the defect are in purple. The gray dash-dot line on each band structure represents the Fermi energy. All plots are shifted such that the top of the pristine-like valence band is at zero at $\mathbf{k} = 0$ (indicated by black dash line). The orbital charge density for the lowest energy unoccupied band is shown below the plots with an isosurface that captures 40% of the density.

 $SO₃$, there is an in-gap state resonant with the conduction bands. This state is slightly delocalized over parts of the tube and slightly dispersive. However, we suspect that this mixing between the defect state and conduction may be artificial and due to DFT self-interaction error which results in mixing of two resonant states, as occurs in bond dissociation.^{[38](#page-5-10)} Thus, we predict that only S and SO can introduce new states into the bandstructure of (6,5) SWCNT, leading to a reduced band gap that varies with the defect.

In summary, we studied four possible SO_x defects (S, \mathcal{S}) SO, SO_2 , and SO_3) adsorbed onto (6,5) SWCNT in order to understand their adsorption characteristics and impact on the tube electronic structure. We determined that the two smaller defects, S and SO are strongly bound, with bond lengths consistent with a covalent bond with S, and that there is a strong dependence on the directionality along the tube for the bonds formed by S. Furthermore, based on the binding energies to (6,5) SWCNT, we determine that a mixture of S and SO dopants are responsible for the red-shifted peaks in the PL spectrum of Figure [1.](#page-1-0) S in the ether-d position is the most strongly bound at 1.6 eV and therefore more likely to form, reducing the gap by ~ 40 meV, slightly smaller than the red-shift of the bright peak in experiment. S in the ether-l is also strongly bound and red-shifts the bandgap by 0.2 eV, consistent with the observed lowenergy shoulder in the PL spectrum. SO is also strongly bound to the CNT by 0.56 eV and red-shifts the gap by 80 meV, consistent with the brightest peak in the PL spectrum. Our analysis indicates that both S and SO

have potential for use as a sp³-type defect for use in tuning the photoluminescence energy of the SWCNT.

I. EXPERIMENTAL AND COMPUTATIONAL METHODS

A. Computational details

The electronic structure and adsorption energy of the pristine and doped SWCNT were computed within density functional theory (DFT) as implemented in the Vienna Ab initio Simulation Package (VASP) $39-43$ $39-43$, with frozen-core projector-augmented wave (PAW) pseudopotentials describing the nuclei and core electrons.[44](#page-5-13)[,45](#page-5-14) The exchange-correlation was treated within the generalized gradient approximation (GGA) of Perdew, Burke, and Ernzerhof $(PBE)^{46}$ $(PBE)^{46}$ $(PBE)^{46}$, with the addition of Grimme D3 van der Waals corrections.^{[47](#page-5-16)} The choice of the PBE functional was made because empirical van der Waals corrections are better suited to PBE, which tends to under-bind, rather than LDA which tends to overbind.^{[48](#page-5-17)[,49](#page-5-18)} All SWCNT were placed in a cubic unit cell with 10 Å of vacuum along the two aperiodic directions. Restricted DFT calculations were performed for all but the 'In-Line-H' $SO₂$ system (See Fig. $2(a)$), which requires spin-polarized unrestricted DFT. Calculations were performed with a Γcentered $1 \times 1 \times 2$ k-point mesh with a plane wave energy cutoff of 400 eV. The structure of the full tube and defect were optimized until all forces were less than 0.01 eV/A . All energies were converged to less than 1×10^{-6} eV. The optimized lattice vector of the pristine (6,5) SWCNT is $\alpha = 32.4$ Å, $b = 20.0$ Å, and $c = 40.4$ Å and was kept constant in the periodic direction (c) for all the defective systems.

Surface binding energies were computed for the bound $(E_{CNT+SOx})$ and isolated (E_{CNT}, E_{SOx}) systems as defined in Eq[.1.](#page-1-1) To obtain the total energy of each system, all three systems were placed in the same cell and all the same computational parameters were applied with the exception of the k-mesh for the SO_x calculation, which was $1 \times 1 \times 1$. For the hydrogen passivated SO_2 structure (structure 6 in Fig. $2(a)$), we subtract out the binding energy associated with the hydrogen atom (-1.41 eV) , which we determined does not interact with $SO₂$. Thus, $E_{\rm b}^{SO_2} = E_{\rm b}^{SO_2+H} + 1.41$ eV.

B. Experimental Details

Chirality-sorted (6,5) SWCNTs were prepared using a two-step phase separation method, as previously described, $50,51$ $50,51$, and transferred into a 1 wt% sodium dodecyl sulfate (SDS) solution via pressure filtration. The samples were subsequently diluted to an optical density of approximately 0.1 at the E_{11} absorption peak of the (6.5) SWCNTs by 0.5 wt% SDS solutions. Functionalization of the SWCNTs was carried out using a mixture of sodium bicarbonate and sodium dithionite. The functionalized solution was then stored in the dark for further optical characterizations.

Absorption spectra were measured using a Varian Cary 50 UV-Vis spectrophotometer. Photoluminescence spectra were obtained with a Nanolog spectrofluorometer (Horiba Jobin Yvon), which is equipped with a liquid nitrogen-cooled InGaAs detector.

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